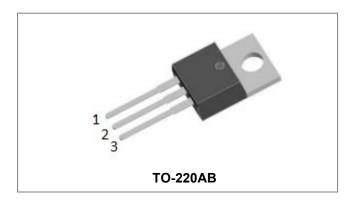


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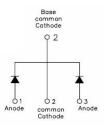
Technical Data Data Sheet N0163, Rev. A



SDUR2030CT ULTRAFAST RECTIFIER



Circuit Diagram



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	-	300	V
DC Blocking Voltage	V _R			
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	10(Per Leg) 20(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	125	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 10A, Pulse, T _J = 25°C	1.17	1.3	V
	V _{F2}	@ 10A, Pulse, T _J = 125°C	0.98	1.2	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_R$ T _J = 25°C	0.05	30	μA
	I _{R2}	$@V_R = rated V_R$ T _J = 125°C	7	1000	μA
Reverse Recovery Time(Per Leg)	t_{rr} I _F =500mA, I _R =1A, and I _{rm} =250mA		31	45	ns

* Pulse width < 300 µs, duty cycle < 2%

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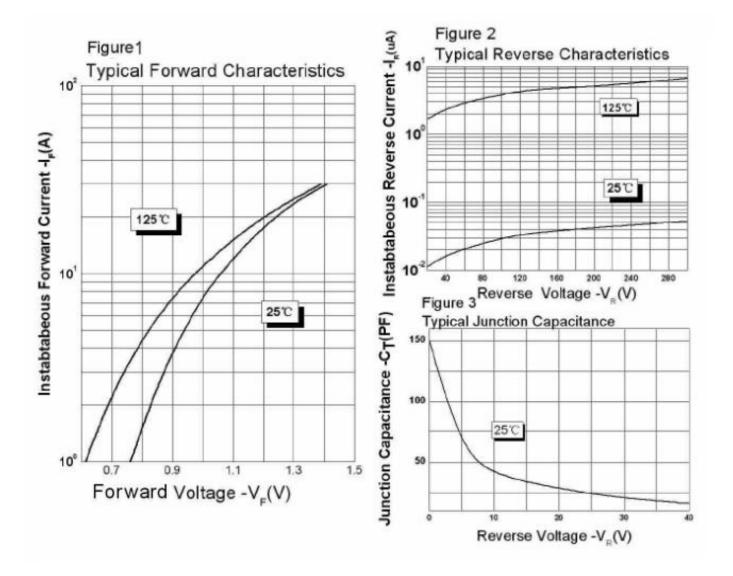
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Technical Data Data Sheet N0163, Rev. A

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	5	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

Ratings and Characteristics Curves





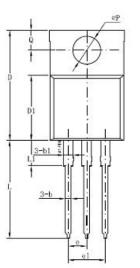
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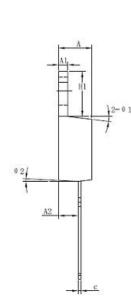
Technical Data Data Sheet N0163, Rev. A



Mechanical Dimensions TO-220AB

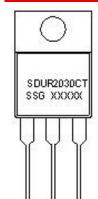






Symbol	Dimensions in millimeters			
	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4 °		

Marking Diagram



Where XXXXX is YYWWL

- = Device Type SDUR
 - = Forward Current (20A) = Reverse Voltage(300V) = Configuration
- SSG
 - = SSG = Year
 - = Week

20 30

СТ

YY

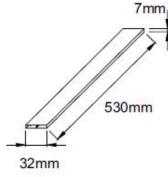
L

WW

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Tube Specification



Ordering Information

Device	Package	Shipping	
SDUR2030CT	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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Technical Data Data Sheet N0163, Rev. A





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